Panasonic

Automation Controls Catalog

4-pin high capacity of 1.1A, I/O isolation voltage of 5,000V

FEATURES

 Greatly increased capacity Continuous load current: 1.1A
Reinforced insulation I/O isolation voltage: 5,000 Vrms
Compact 4-pin DIP type
The improved performance relative to mercury or mechanical relays Photo MOS[®] GU 1 Form A High Capacity (AQY212GH)

TYPICAL APPLICATIONS

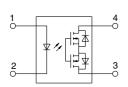
Measuring instruments

• Security and disaster-preventing system: use in I/O for alarm and security devices, etc.



mm inch

(Height includes standoff)



RoHS compliant

TYPES

	Output rating*			Par	- Packing quantity			
			Through hole terminal	Surface-mount terminal				
	Load Load voltage		Tube packing style		Tape and reel packing style			
					Picked from the 1/2-pin side	Picked from the 3/4-pin side	Tube	Tape and reel
AC/DC dual use	60 V	1.1 A	AQY212GH	AQY212GHA	AQY212GHAX	AQY212GHAZ	1 tube contains 100 pcs. 1 batch contains 1,000 pcs.	1,000 pcs.

*Indicate the peak AC and DC values.

Note: For space reasons, the three initial letters of the part number "AQY", the surface mount terminal shape indicator "A" and the packing style indicator "X" or "Z" are not marked on the device.

RATING

1. Absolute maximum ratings (Ambient temperature: 25°C 77°F)

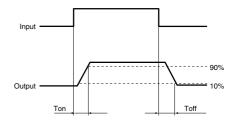
	Item	Symbol	AQY212GH(A)	Remarks
	LED forward current	lF	50 mA	
	LED reverse voltage	VR	5 V	
nput	Peak forward current	IFP	1 A	f = 100 Hz, Duty factor = 0.1%
	Power dissipation	Pin	75 mW	
	Load voltage (peak AC)	VL	60 V	
S	Continuous load current	IL I	1.1 A	Peak AC, DC
Dutput	Peak load current	Ipeak	3.0 A	100ms (1 shot), V∟ = DC
	Power dissipation	Pout	500 mW	
otal power dissipatior		Рт	550 mW	
O isolation voltage		Viso	5,000 Vrms	
mbienttemperature	Operating	Topr	−40 to +85°C −40 to +185°F	(Non-icing at low temperatures
mbient temperature	Storage	Tstg	-40 to +100°C -40 to +212°F	

GU 1 Form A High Capacity (AQY212GH)

2. Electrical characteristics	(Ambient temperature: 25°C 77°F)	

Item			Symbol	AQY212GH(A)	Condition	
Input	LED operate current	Typical	Fon	1.1 mA	IL = 100mA	
	LED operate current	Maximum	I⊦on	3 mA	1L = 100MA	
	LED turn off current	Minimum	Foff	0.3 mA	I∟ = 100mA	
	LED turn on current	Typical	IFott	1.0 mA	IL = TOOTTA	
	LED dropout voltage	Typical	VF	1.32 V (1.14 V at I⊧ = 5 mA)	l⊧ = 50 mA	
		Maximum	۷F	1.5 V	IF = 50 IIIA	
Output	On resistance	Typical	Ron	0.34 Ω	I⊧ = 5 mA I∟ = Max. Within 1 s	
	On resistance	Maximum	non	0.7 Ω		
	Off state leakage current	Maximum	Leak	1 μΑ	I⊧ = 0 mA V∟ = Max.	
	Turn on time*	Typical	- Ton	1.3 ms	l⊧ = 5 mA	
	ium on ume	Maximum		5.0 ms	I∟ = 100 mA V∟ = 10 V	
Transfer	Turn off time*	Typical	Toff	0.1 ms	I⊧ = 5 mA I∟ = 100 mA	
characteristics		Maximum	loff	0.5 ms	IL = 100 MA VL = 10 V	
		Typical	Ciso	0.8 pF	f = 1 MHz	
	I/O capacitance	Maximum	Ciso	1.5 pF	V _B = 0 V	
	Initial I/O isolation resistance	Minimum	Riso	1,000 MΩ	500 V DC	

*Turn on/Turn off time



3. Recommended operating conditions (Ambient temperature: 25°C 77°F) Please use under recommended operating conditions to obtain expected characteristics.

I	tem	Symbol	Symbol Min. Max.		
LED	current	lF	5	30	mA
	Load voltage (Peak AC)	VL	—	48	V
AQY212GH(A)	Continuous load current	IL.	_	1.1	A

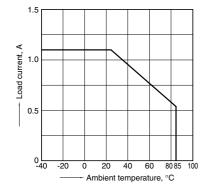
■ These products are not designed for automotive use.

If you are considering to use these products for automotive applications, please contact your local Panasonic Corporation technical representative.

REFERENCE DATA

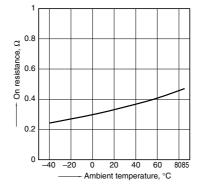
1. Load current vs. ambient temperature characteristics

Allowable ambient temperature: -40 to +85°C $$-40\ to\ +185°F$$



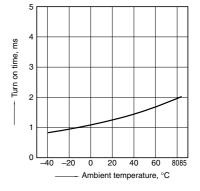
2. On resistance vs. ambient temperature characteristics

Measured portion: between terminals 3 and 4; LED current: 5 mA; Load voltage: Max. (DC) Continuous load current: Max.(DC)



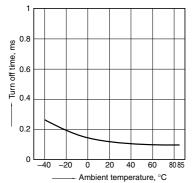
3. Turn on time vs. ambient temperature characteristics

LED current: 5 mA; Load voltage: 10 V (DC); Continuous load current: 100 mA (DC)

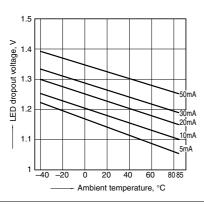


4. Turn off time vs. ambient temperature characteristics

LED current: 5 mA; Load voltage: 10 V (DC); Continuous load current: 100 mA (DC)



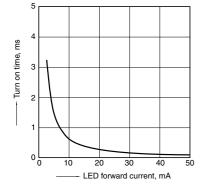
7. LED dropout voltage vs. ambient temperature characteristics LED current: 5 to 50 mA

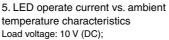


10. Turn on time vs. LED forward current characteristics

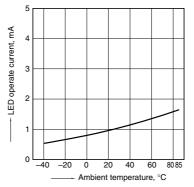
Measured portion: between terminals 3 and 4; Load voltage: 10 V (DC);

Continuous load current: 100 mA (DC); Ambient temperature: 25°C 77°



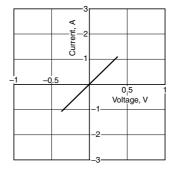


Continuous load current: 100mA (DC)



8. Current vs. voltage characteristics of output at MOS portion

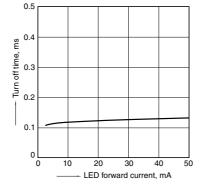
Measured portion: between terminals 3 and 4; Ambient temperature: 25°C 77°F



11. Turn off time vs. LED forward current characteristics

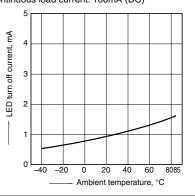
Measured portion: between terminals 3 and 4; Load voltage: 10 V (DC);

Continuous load current: 100 mA (DC); Ambient temperature: 25°C 77



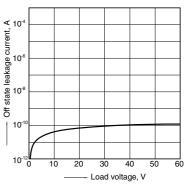
6. LED turn off current vs. ambient temperature characteristics

Load voltage: 10 V (DC); Continuous load current: 100mA (DC)



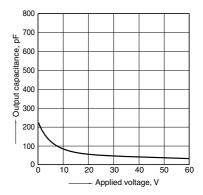
9. Off state leakage current vs. load voltage characteristics

Measured portion: between terminals 3 and 4; Ambient temperature: 25°C 77°F



12. Output capacitance vs. applied voltage characteristics

Measured portion: between terminals 3 and 4; Frequency: 1 MHz; Ambient temperature: 25°C 77°F



-3-

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